

9097250 TOSHIBA (DISCRETE/OPTO)

56C 07941

D T-33-09

2SD1406

SILICON NPN TRIPLE DIFFUSED TYPE

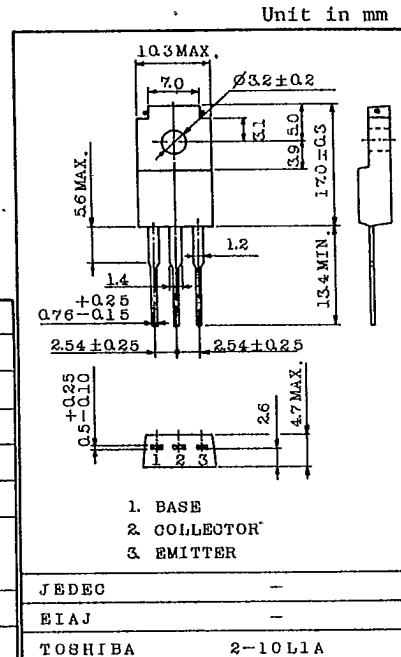
AUDIO FREQUENCY POWER AMPLIFIER APPLICATIONS.

FEATURES:

- High DC Current Gain : $h_{FE}=300(\text{Max.})(V_{CE}=5V, I_C=0.5A)$
- Low Saturation Voltage
: $V_{CE}(\text{sat})=1.0V(\text{Max.})(I_C=3A, I_B=0.3A)$
- High Power Dissipation : $P_C=25W (T_c=25^\circ C)$
- Complementary to 2SB1015

MAXIMUM RATINGS ($T_a=25^\circ C$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	60	V
Collector-Emitter Voltage	V_{CEO}	60	V
Emitter-Base Voltage	V_{EBO}	7	V
Collector Current	I_C	3	A
Base Current	I_B	0.5	A
Collector Power Dissipation	P_C	$T_a=25^\circ C$ 2.0	W
		$T_c=25^\circ C$ 25	
Junction Temperature	T_j	150	$^\circ C$
Storage Temperature Range	T_{stg}	-55 ~ 150	$^\circ C$



Weight : 2.1g

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ C$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB}=60V, I_E=0$	-	-	100	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=7V, I_C=0$	-	-	100	μA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=50mA, I_B=0$	60	-	-	V
DC Current Gain	$h_{FE}(\text{Note})$	$V_{CE}=5V, I_C=0.5A$	60	-	300	-
Collector Emitter Saturation Voltage	$V_{CE}(\text{sat})$	$I_C=3A, I_B=0.3A$	-	0.25	1.0	V
Base-Emitter Voltage	V_{BE}	$V_{CE}=5V, I_C=0.5A$	-	0.7	1.0	V
Transition Frequency	f_T	$V_{CE}=5V, I_C=0.5A$	-	3.0	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10V, I_E=0, f=1MHz$	-	70	-	pF
Switching Time	Turn-on Time	t_{on}	-	0.8	-	μs
	Storage Time	t_{stg}	-	1.5	-	
	Fall Time	t_f	-	0.8	-	

$I_{B1} = -I_{B2} = 0.2A$
 DUTY CYCLE < 1%
 $V_{CC} = 30V$

Note : h_{FE} Classification O : 60 ~ 120, Y : 100 ~ 200, GR : 150 ~ 300

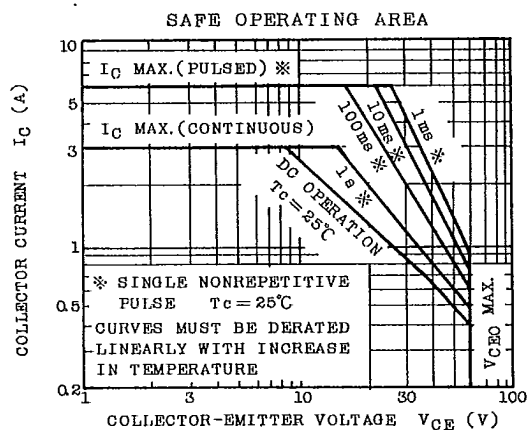
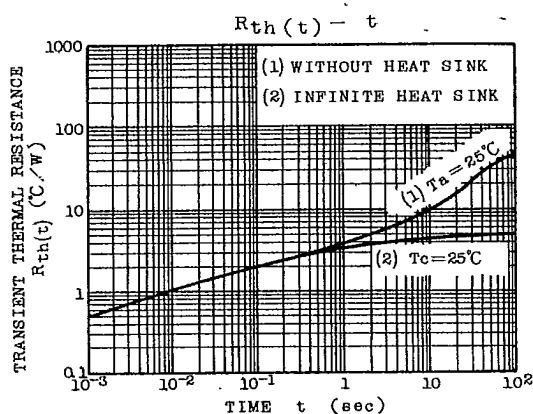
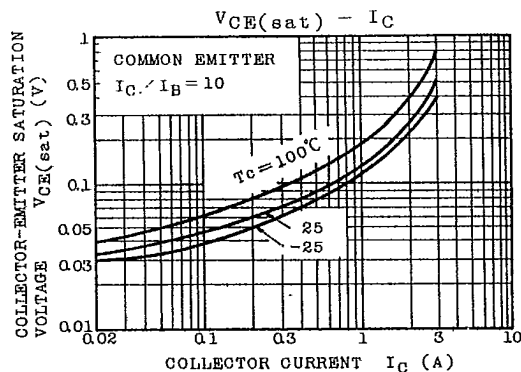
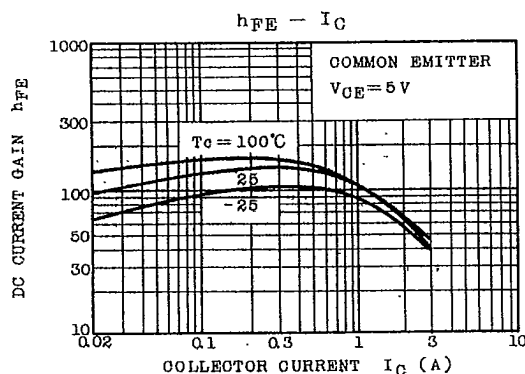
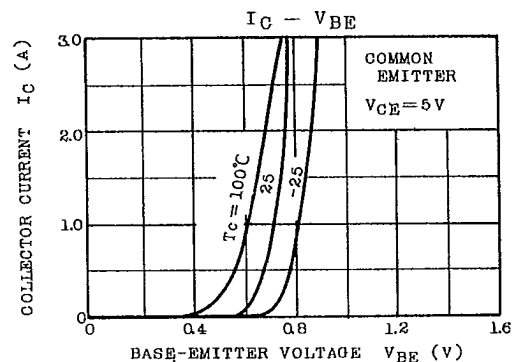
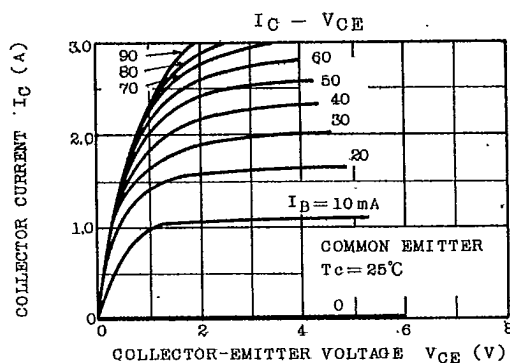
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